NSN 5961-00-137-4696

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-137-4696

Inclosure Material:

Metal

Overall Length:

0.375 inches

Overall Diameter:

0.875 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

100.0 collector to base voltage, dc and 80.0 collector to base voltage/static/emitter open and 27.0 emitter to base, rms

Current Rating Per Characteristic:

10.00 amperes source cutoff current and 4.00 amperes zero-gate-voltage source current of standard range

Power Rating Per Characteristic:

150.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Test Data Document:

13499-352-0677 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

2 uninsulated wire lead and 1 case

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0